

International  
**IR** Rectifier  
 SCHOTTKY RECTIFIER  
 HIGH EFFICIENCY SERIES

PD-20351H

15CLQ100  
 JANS1N703CCU1  
 JANTX1N703CCU1  
 JANTXV1N703CCU1

35A, 100V

Ref: MIL-PRF-19500/730

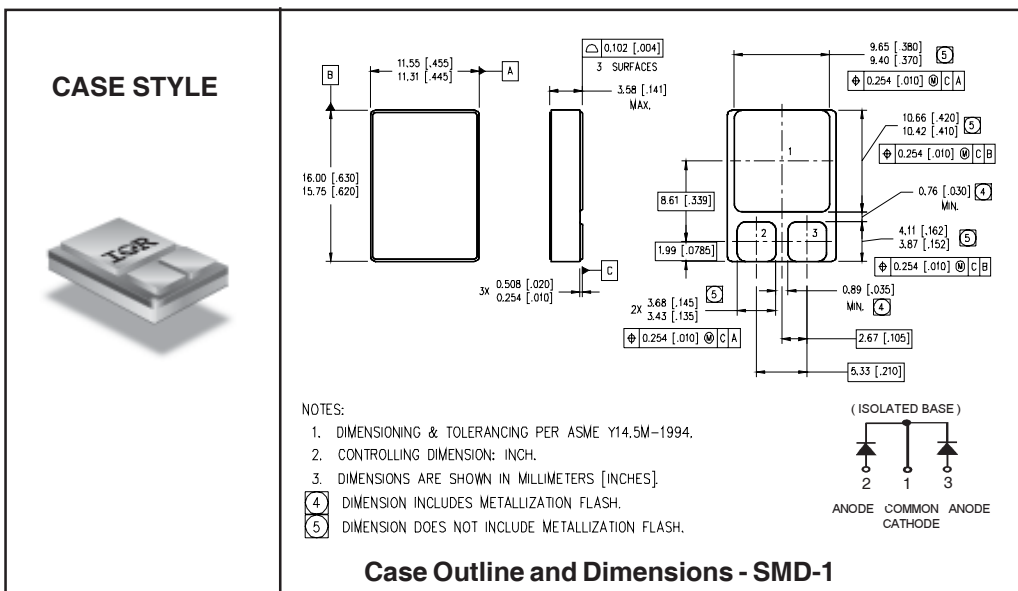
**Major Ratings and Characteristics**

Characteristics	1N703CCU1	Units
$I_{F(AV)}$	35	A
$V_{RRM}$ (Per Leg)	100	V
$I_{FSM}$ @ $t_p = 8.3ms$ half-sine (Per Leg)	250	A
$V_F$ @ 5.0Apk, $T_J = 125^\circ C$ (Per Leg)	0.53	V
$T_J, T_{stg}$ Operating and storage	-65 to 150	$^\circ C$

**Description/Features**

The 1N703CCU1 center tap Schottky rectifier has been expressly designed to meet the rigorous requirements of high reliability environments. It is packaged in the hermetic surface mount SMD-1 ceramic package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source controlled drawings to TX, TXV and S levels.

- Hermetically Sealed
- Center Tap
- Low Forward Voltage Drop
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long Term Reliability
- Surface Mount
- Lightweight



**Voltage Ratings**

Part number	1N7037CCU1
V <sub>R</sub> Max. DC Reverse Voltage (V) (Per Leg)	100
V <sub>RWM</sub> Max. Working Peak Reverse Voltage (V) (Per Leg)	

**Absolute Maximum Ratings**

Parameters	Limits	Units	Conditions
I <sub>F(AV)</sub> Max. Average Forward Current See Fig. 5	35	A	50% duty cycle @ T <sub>C</sub> = 100°C, rectangular waveform
I <sub>FSM</sub> Max. Peak One Cycle Non - Repetitive Surge Current (Per Leg)	250	A	@ t <sub>p</sub> = 8.3 ms half-sine

**Electrical Specifications**

Parameters	Limits	Units	Conditions	
V <sub>FM</sub> Max. Forward Voltage Drop (Per Leg) ①	1.35	V	@ 35A	T <sub>J</sub> = -55°C
	0.90	V	@ 15A	T <sub>J</sub> = 25°C See Fig. 1
	1.22	V	@ 35A	
	1.00	V	@ 35A	T <sub>J</sub> = 125°C See Fig. 1
I <sub>RM</sub> Max. Reverse Leakage Current (Per Leg) See Fig. 2 ①	0.5	mA	T <sub>J</sub> = 25°C	V <sub>R</sub> = rated V <sub>R</sub>
	15	mA	T <sub>J</sub> = 125°C	
C <sub>T</sub> Max. Junction Capacitance (Per Leg)	600	pF	V <sub>R</sub> = 5V <sub>DC</sub> (1MHz, 25°C)	
L <sub>S</sub> Typical Series Inductance (Per Leg)	5.9	nH	Measured from center of cathode pad to center of anode pad	

**Thermal-Mechanical Specifications**

Parameters	Limits	Units	Conditions
T <sub>J</sub> Max. Junction Temperature Range	-65 to 150	°C	
T <sub>stg</sub> Max. Storage Temperature Range	-65 to 150	°C	
R <sub>thJC</sub> Max. Thermal Resistance, Junction to Case (Per Leg)	1.60	°C/W	DC operation See Fig. 4
R <sub>thJC</sub> Max. Thermal Resistance, Junction to Case (Per Package)	0.80	°C/W	DC operation
wt Weight (Typical)	2.4	g	
Die Size	125X125	mils	
Case Style	SMD-1		

① Pulse Width &lt; 300μs, Duty Cycle &lt; 2%

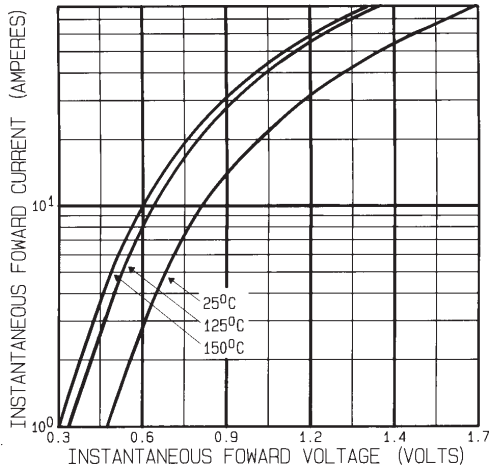


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

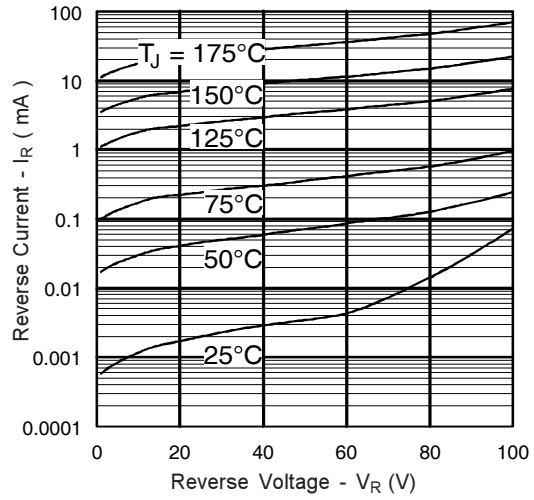


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage (Per Leg)

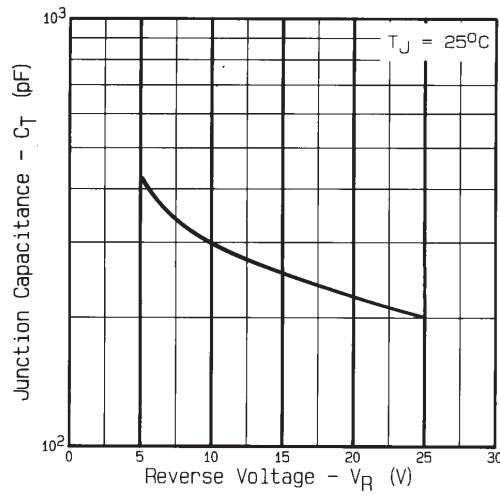


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

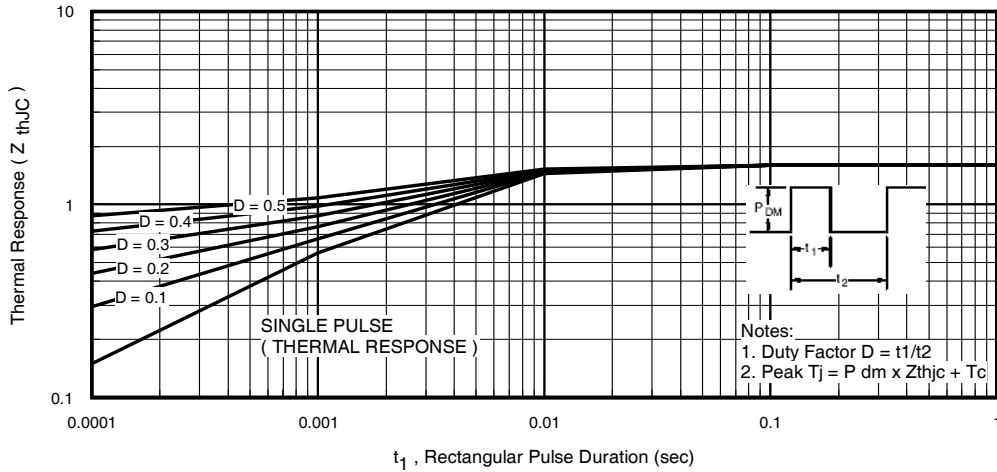


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

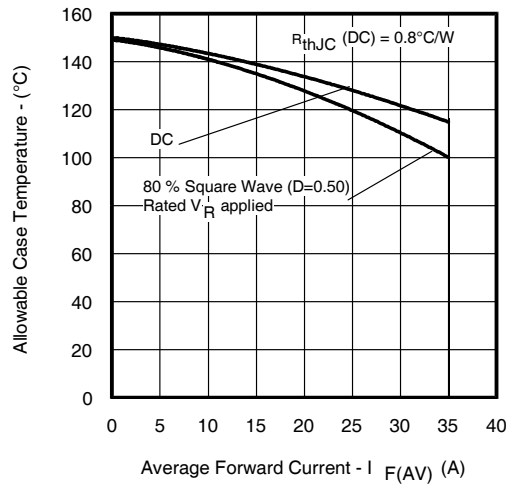


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current